Technical Data
Data Sheet N2353, Rev. C

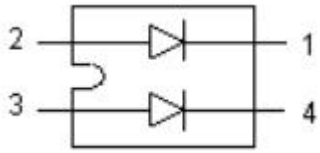
SK2S200-200 Power Schottky Rectifier

SOT-227

Features

- International standard package SOT-227
- Extremely low switching losses
- Low I_{RM} -values
- Copper internally DBC isolated
- Base plate: Nickel plated; Terminals: Nickel plated
- UL approved file E517293
- This is a Pb − Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Rectifiers in switch mode power Supplies(SMPS)
- Free wheeling diode in low voltage Converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced Protection circuits
- Low noise switching
- Low losses

Maximum Ratings(limiting values, T_C =25°C unless otherwise specified) :

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	200	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @T_C =105°C, rectangular wave form	100(Per Leg) 200(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I_{FSM}	8.3 ms, half Sine pulse	1400	A

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RoHS

Electrical Characteristics:

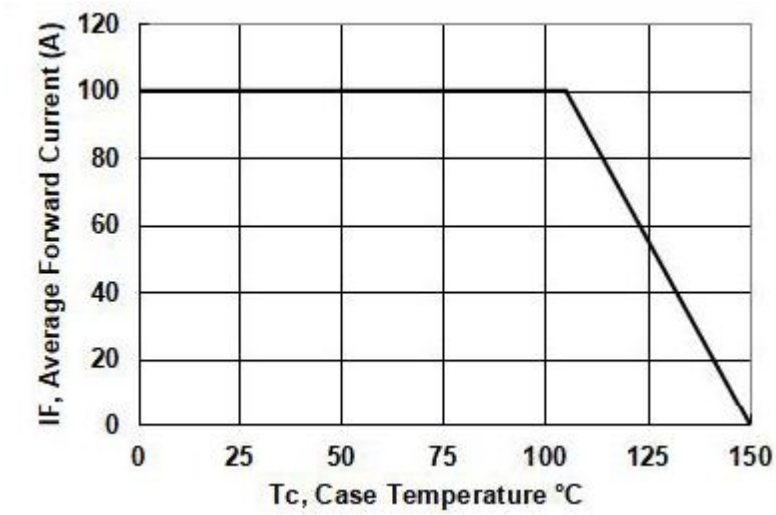
Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Per Leg)*	V_{F1}	@ 100A, Pulse, T_J = 25 °C @ 200A, Pulse, T_J = 25 °C	0.90 1.03	0.95 1.30	V
	V_{F2}	@ 100A, Pulse, T_J = 125 °C @ 200A, Pulse, T_J = 125 °C	0.76 0.91	0.85 1.10	V
Reverse Current(Per Leg)*	I_{R1}	@V_R = rated V_R, T_J = 25 °C	0.0005	0.5	mA
	I_{R2}	@V_R = rated V_R, T_J = 125 °C	0.4	15	mA
Isolation Breakdown Voltage(R.M.S)	Visol	Ac.50Hz; R.M.S;1min, T_J = 25 °C	-	2500	V
		Ac.50Hz; R.M.S; 1sec, T_J = 25 °C	-	3500	

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Thermal Resistance Junction to Case(Peg Device)	$R_{\theta JC}$	DC operation	0.4	°C/W
Mounting torque(M4)	M_D	-	1.1-1.5/9-13	Nm/ lb.in.
Terminal connection torque(M4)			1.1-1.5/9-13	
Typical Approximate Weight	wt	-	30	g

Ratings and Characteristics Curves



Forward Current VS Case temperature Diode

Figure1
Typical Forward Characteristics

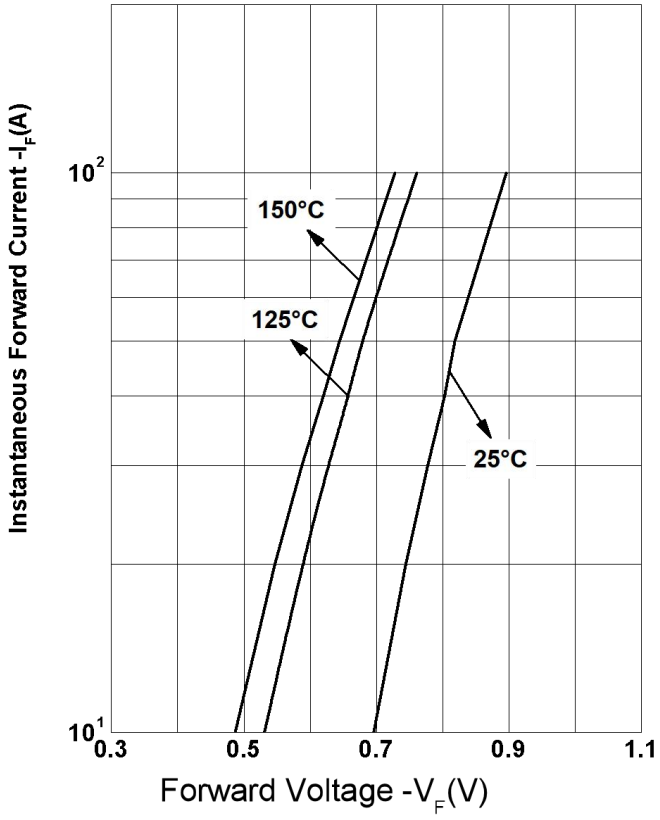


Figure 2
Typical Reverse Characteristics

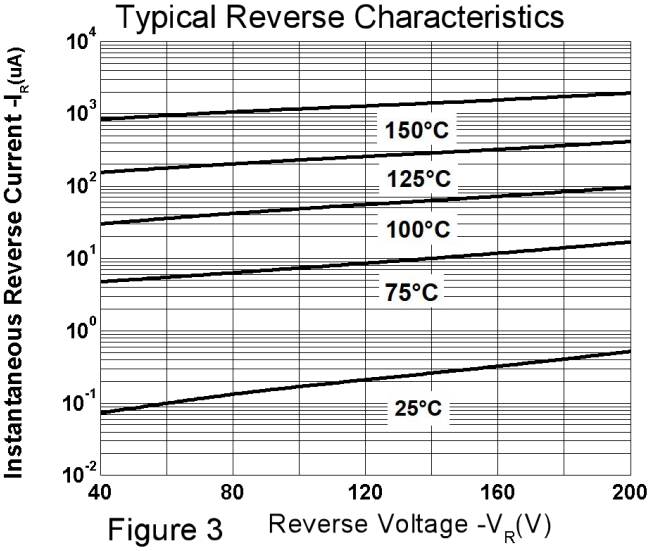
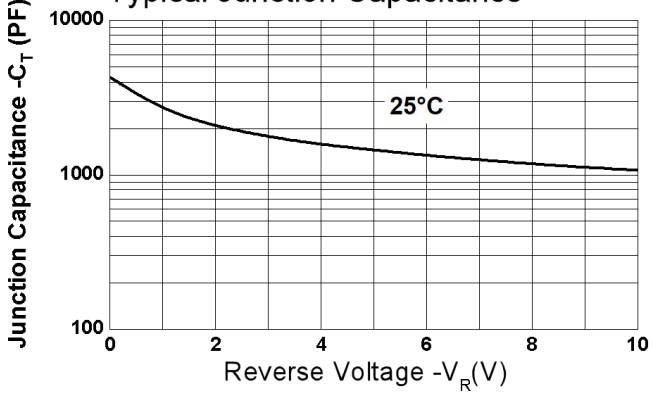


Figure 3
Typical Junction Capacitance



SK2S200-200

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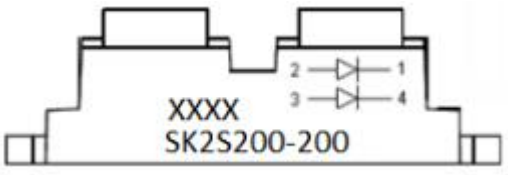
Ordering Information

Device	Package	Shipping
SK2S200-200	SOT-227 (Pb-Free)	36pcs /BULK

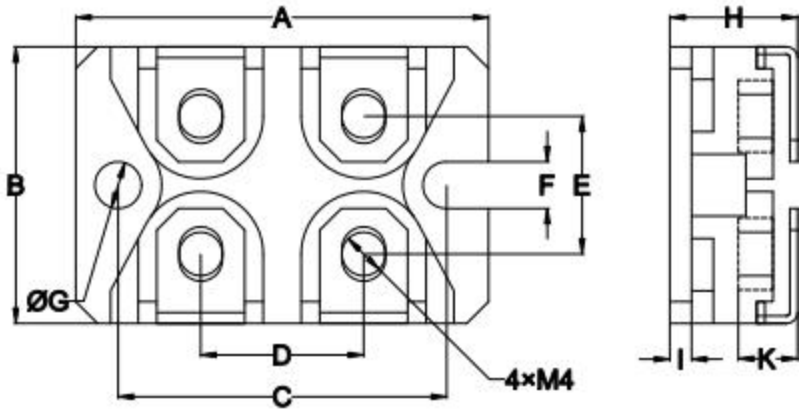
Marking Diagram



Where XXXX is YYWW

S = SMC's Power Module
K = SOT-227 Package
2 = Circuit Configuration
S = Schottky Rectifier
200 = Forward Current (200A)
200 = Reverse Voltage (200V)
YY = Year
WW = Week

Mechanical Dimensions SOT-227(Millimeters)



SYMBOL	Dimensions in millimeters	
	Min.	Max.
A	37.8	38.2
B	24.8	25.21
C	29.9	30.55
D	14.5	15.5
E	12.2	13.45
F	4.1	4.31
G	φ4.1	φ4.31
H	11	12.5
I	1.9	2.1
K	4.3	6.5

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